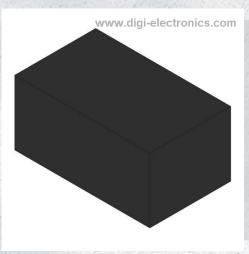


NX7002BKM315 Datasheet



DiGi Electronics Part Number Manufacturer Manufacturer Product Number

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Description

Detailed Description

NX7002BKM315-DG

NXP USA Inc.

NX7002BKM315

SMALL SIGNAL N-CHANNEL MOSFET

N-Channel 60 V 350mA (Ta) 350mW (Ta), 3.1W (Tc) Surface Mount DFN1006-3

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
NX7002BKM315	NXP USA Inc.
Series:	Product Status:
	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
60 V	350mA (Ta)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
5V, 10V	2.80hm @ 200mA, 10V
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:
2.1V @ 250µA	1 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	23.6 pF @ 10 V
FET Feature:	Power Dissipation (Max):
	350mW (Ta), 3.1W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Supplier Device Package:	Package / Case:
DFN1006-3	SC-101, SOT-883

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
Not applicable	1 (Unlimited)
REACH Status:	ECCN:
Vendor Undefined	EAR99
HTSUS:	
8541.21.0095	



NX7002BKM 60 V, N-channel Trench MOSFET

3 December 2014

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006-3 (SOT883) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic-level compatible
- Very fast switching
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2kV HBM

3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Quie	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	60	V
V _{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	-	350	mA
Static characte	Static characteristics						
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I _D = 200 mA; T _j = 25 °C		-	2.2	2.8	Ω

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

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NX7002BKM

60 V, N-channel Trench MOSFET

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	1	D
2	S	source	2 2 3	
3	D	drain	Transparent top view DFN1006-3 (SOT883)	G S 017aaa255

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
NX7002BKM	DFN1006-3	DFN1006-3: leadless ultra small plastic package; 3 solder lands	SOT883				

7. Marking

Table 4. Marking codes	
Type number	Marking code
NX7002BKM	WZ

NX7002BKM

60 V, N-channel Trench MOSFET

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	60	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	350	mA
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	200	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	0.9	А
P _{tot} total power dissip	total power dissipation	T _{amb} = 25 °C	[2]	-	350	mW
			[1]	-	680	mW
		T _{sp} = 25 °C		-	3100	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-dra	in diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	200	mA

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².
Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

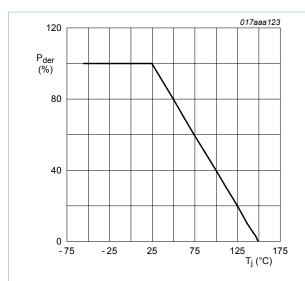
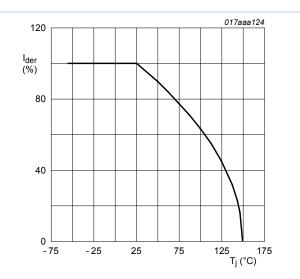


Fig. 1. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

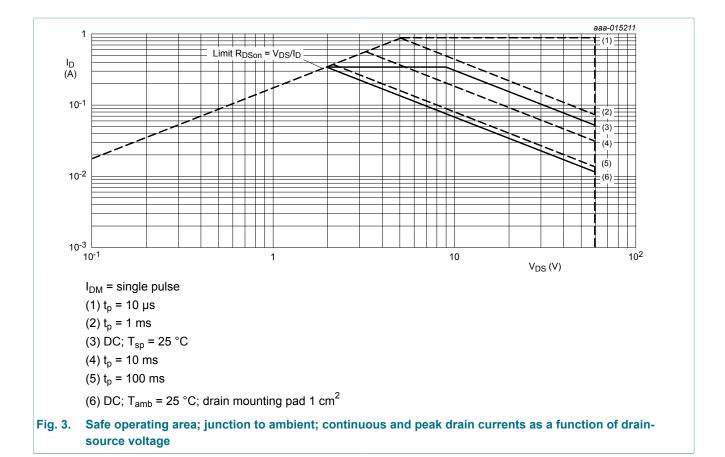




$$I_{der} = \frac{I_D}{I_{D(25^\circ C)}} \times 100 \%$$

NX7002BKM

60 V, N-channel Trench MOSFET



9. Thermal characteristics

Table 6. The	rmal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R _{th(j-a)} thermal resistance			[1]	-	314	360	K/W
	from junction to ambient		[2]	-	159	180	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	35	40	K/W

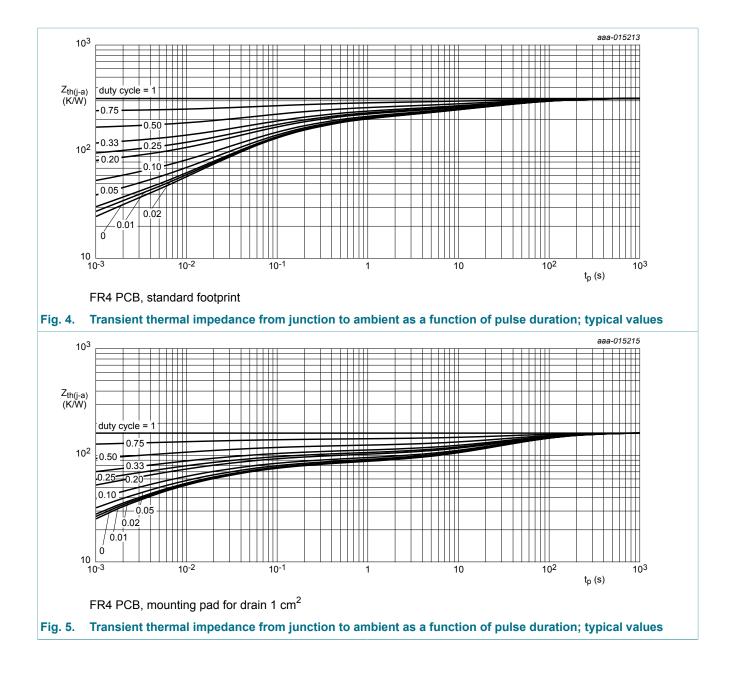
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

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NX7002BKM

60 V, N-channel Trench MOSFET



NX7002BKM

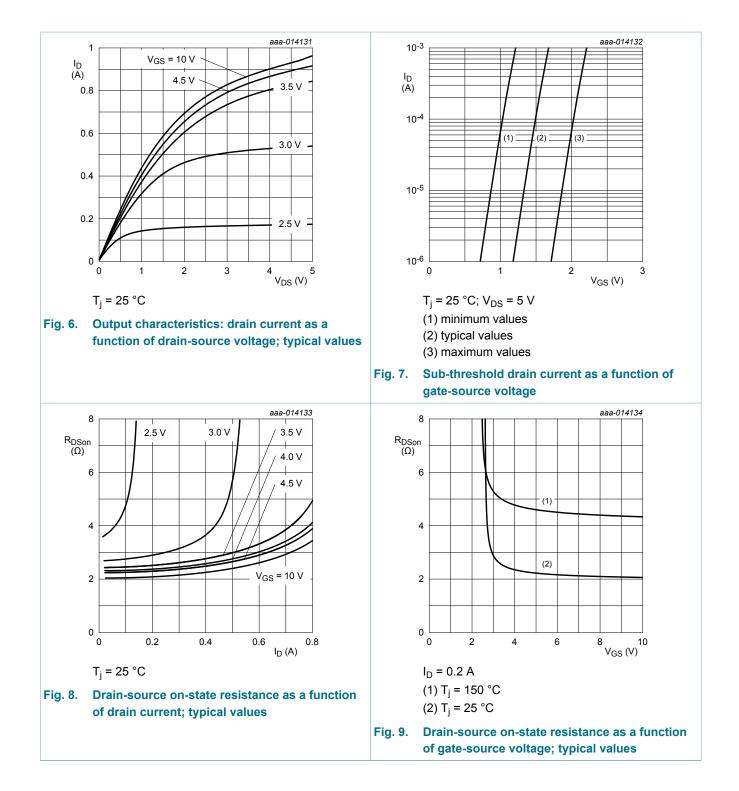
60 V, N-channel Trench MOSFET

10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics	I				
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	60	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	1.1	1.6	2.1	V
I _{DSS}	drain leakage current	V_{DS} = 60 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μA
		V_{GS} = 10 V; V_{DS} = 0 V; T_j = 25 °C	-	-	1	μA
		V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-1	μA
		V_{GS} = 5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	0.3	μA
		V _{GS} = -5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-0.3	μA
R _{DSon} drain-source resistance	drain-source on-state	V_{GS} = 10 V; I _D = 200 mA; T _j = 25 °C	-	2.2	2.8	Ω
	resistance	V _{GS} = 10 V; I _D = 100 mA; T _j = 150 °C	-	4.5	5.7	Ω
		V _{GS} = 5 V; I _D = 200 mA; T _j = 25 °C	-	2.5	3.2	Ω
9 _{fs}	forward transconductance	V_{DS} = 10 V; I _D = 200 mA; T _j = 25 °C	-	600	-	mS
R _G	internal gate resistance (AC)	f = 2.5 MHz	-	2.5	-	Ω
Dynamic ch	aracteristics	· · ·	I	1		
Q _{G(tot)}	total gate charge	V_{DS} = 30 V; I _D = 200 mA; V _{GS} = 10 V;	-	1	-	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.12	-	nC
Q _{GD}	gate-drain charge		-	0.18	-	nC
C _{iss}	input capacitance	V_{DS} = 10 V; f = 1 MHz; V_{GS} = 0 V;	-	23.6	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	4.6	-	pF
C _{rss}	reverse transfer capacitance		-	3	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 50 V; I _D = 200 mA; V _{GS} = 10 V;	-	4.7	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	4.3	-	ns
t _{d(off)}	turn-off delay time		-	6.9	-	ns
t _f	fall time	-	-	2.9	-	ns
Source-drai	n diode	1	I	1	_1	
V _{SD}	source-drain voltage	I _S = 200 mA; V _{GS} = 0 V; T _i = 25 °C	-	0.87	1.2	V

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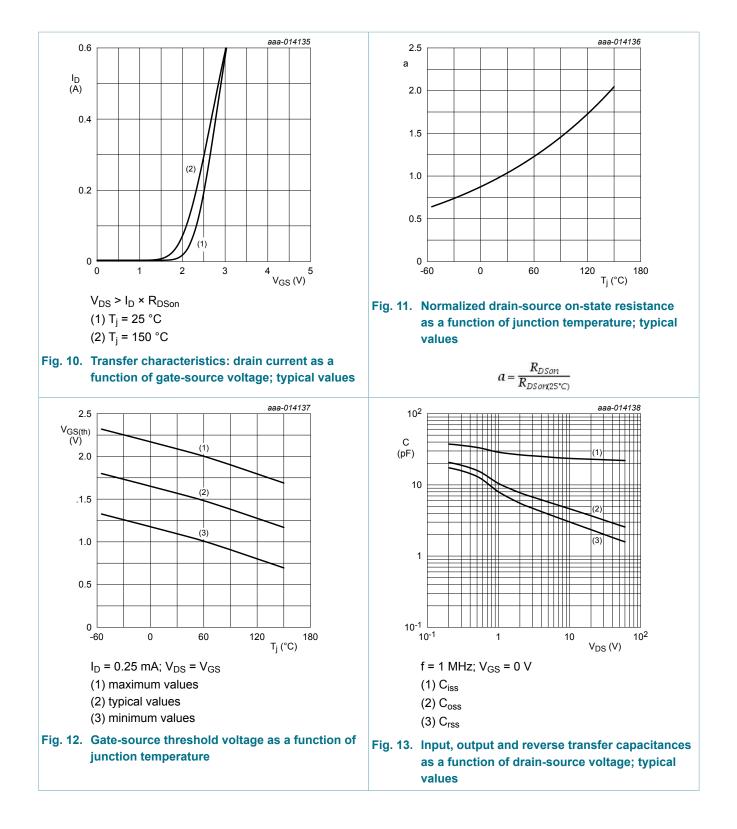
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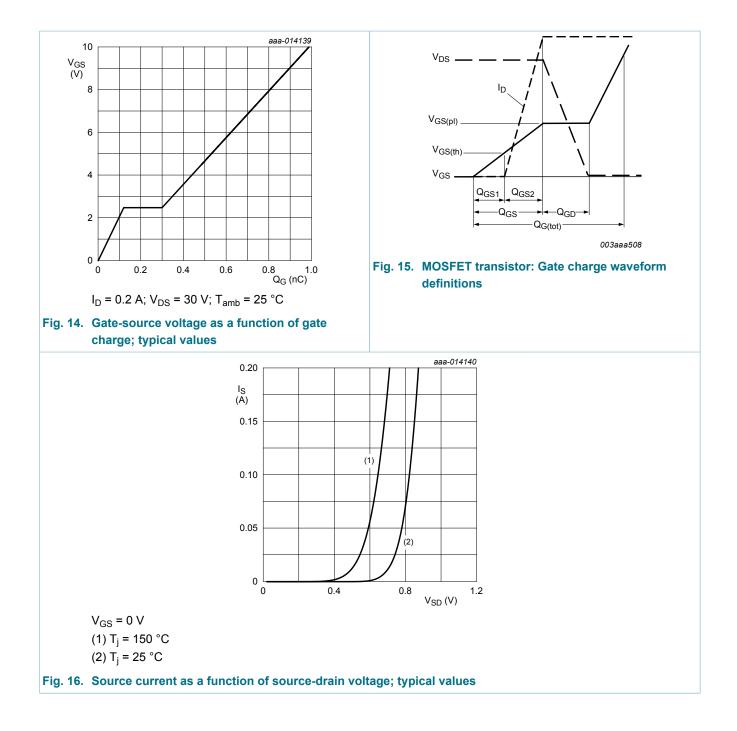


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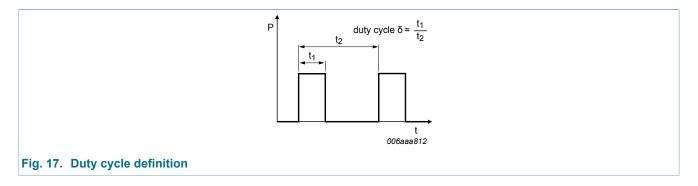
60 V, N-channel Trench MOSFET



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11. Test information



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12. Package outline

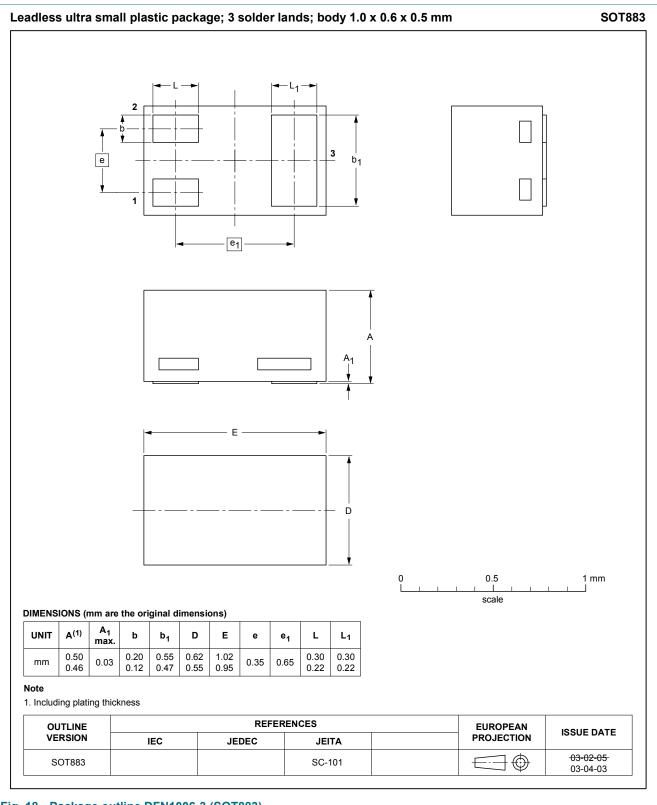


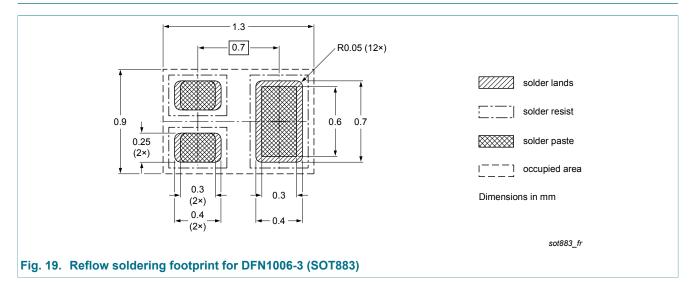
Fig. 18. Package outline DFN1006-3 (SOT883)

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60 V, N-channel Trench MOSFET

13. Soldering



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14. Revision history

Table 8. Revision his	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
NX7002BKM v.2	20141203	Product data sheet	-	NX7002BKM v.1
Modification:	Figure 3 updated			
NX7002BKM v.1	20141001	Product data sheet	-	-

NX7002BKM

60 V, N-channel Trench MOSFET

15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Product data sheet

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60 V, N-channel Trench MOSFET

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	Features and benefits

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